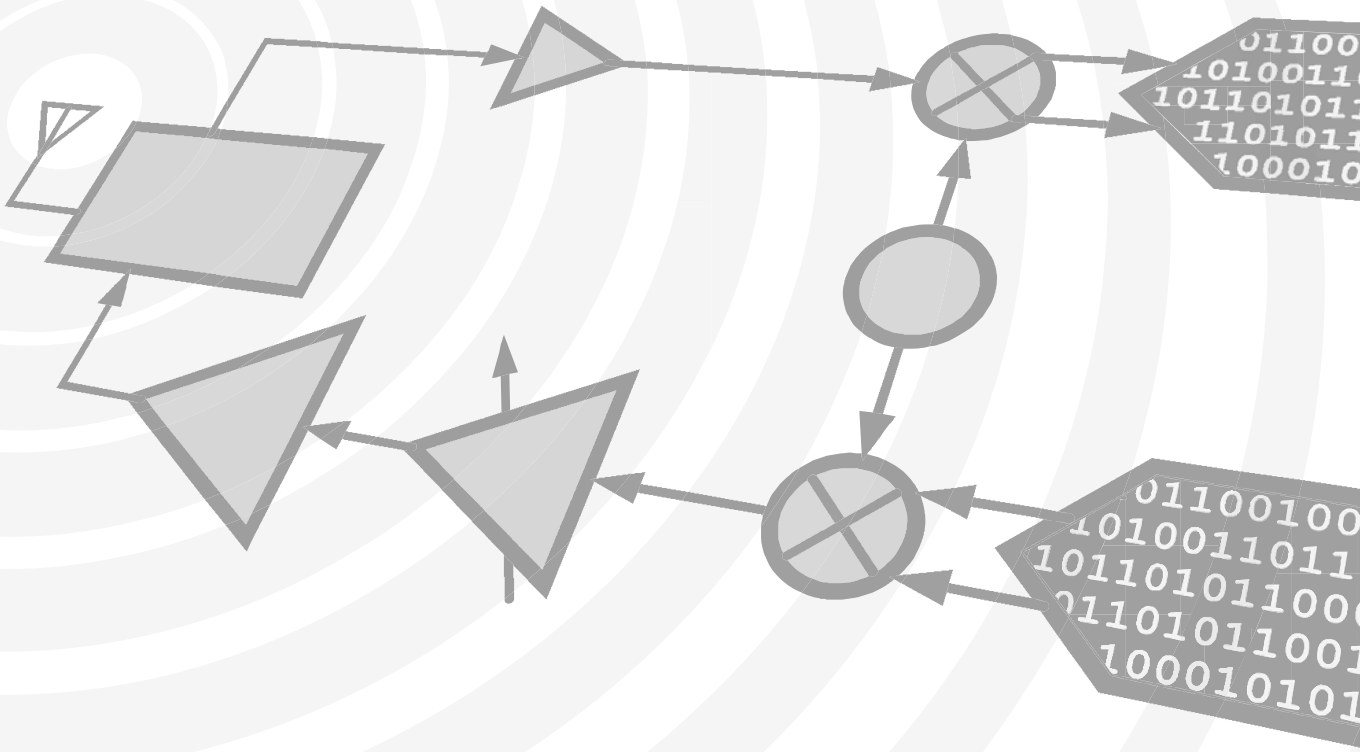
ANALOG DEVICES

Hittite MICROWAVE PRODUCTS FROM ANALOG DEVICES

Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



www.analog.com

www.hittite.com

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HMC346LC3B

GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz

Typical Applications

The HMC346LC3B is ideal for:

- Test Instrumentation
- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar, & ECM

Features

Wide Bandwidth: DC - 18 GHz

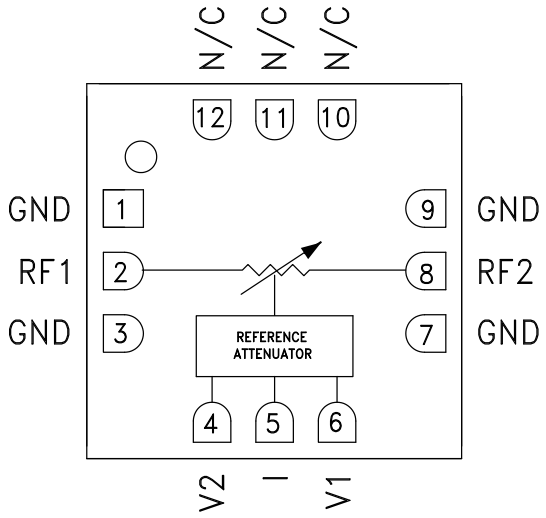
Low Phase Shift vs. Attenuation

30 dB Attenuation Range

Simplified Voltage Control

RoHS Compliant 3 x 3 mm SMT Package

Functional Diagram



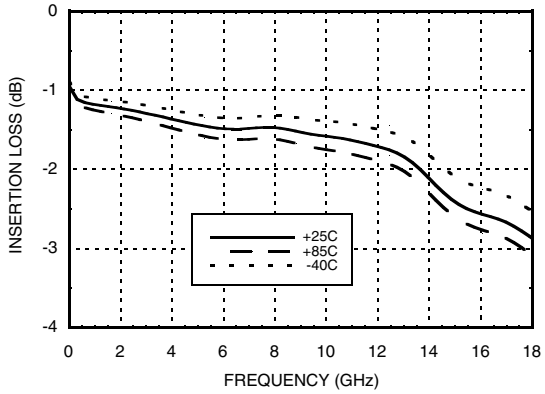
General Description

The HMC346LC3B is an absorptive Voltage Variable Attenuator (VVA) in a leadless “Pb free” RoHS compliant SMT mount ceramic package operating from DC - 18 GHz. It features an on-chip reference attenuator for use with an external op-amp to provide simple single voltage attenuation control, 0 to -3V. The device is ideal in designs where an analog DC control signal must control RF signal levels over a 30 dB amplitude range. The HMC346LC3B allows the use of surface mount manufacturing techniques.

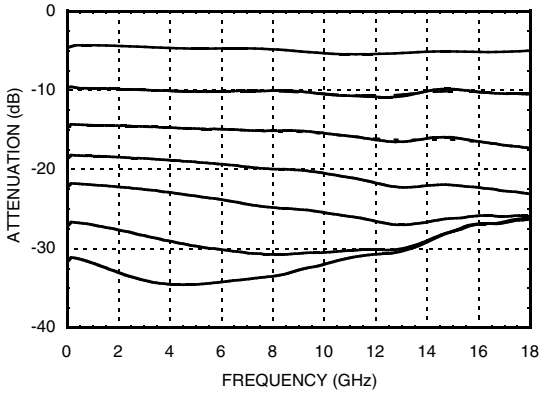
Electrical Specifications, T_A = +25° C, 50 Ohm system

Parameter		Min	Typical	Max	Units
Insertion Loss	DC - 10 GHz DC - 14 GHz DC - 18 GHz		1.5 2.2 2.8	2.0 2.7 3.5	dB dB dB
Attenuation Range	DC - 12 GHz DC - 18 GHz	26 22	30 26		dB dB
Return Loss	DC - 18 GHz		10		dB
Input Power for 0.25 dB Compression (0.5 - 18 GHz)	Min. Atten: Atten. >2 dB:		+8 -4		dBm dBm
Input Third Order Intercept (0.5 - 18 GHz) (Two-tone Input Power = -8 dBm Each Tone)	Min. Atten: Atten. >2 dB:		+25 +10		dBm dBm
Switching Characteristics	tRISE, tFALL (10/90% RF): tON, tOFF (50% CTL to 10/90% RF):		2 8		ns ns

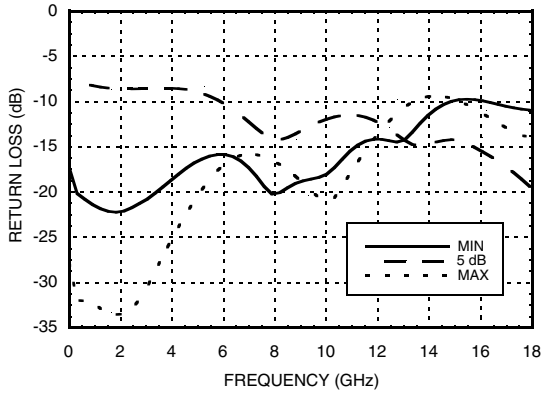
Insertion Loss vs. Temperature



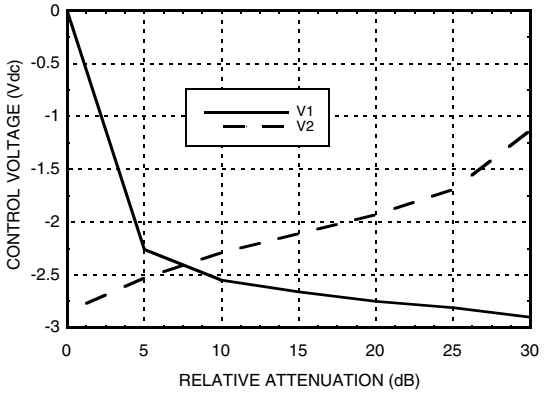
Relative Attenuation



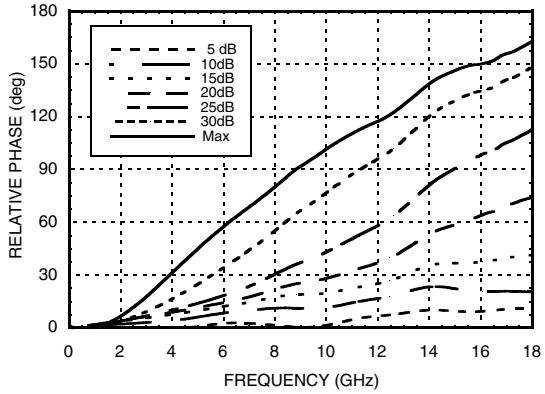
Return Loss vs. Attenuation



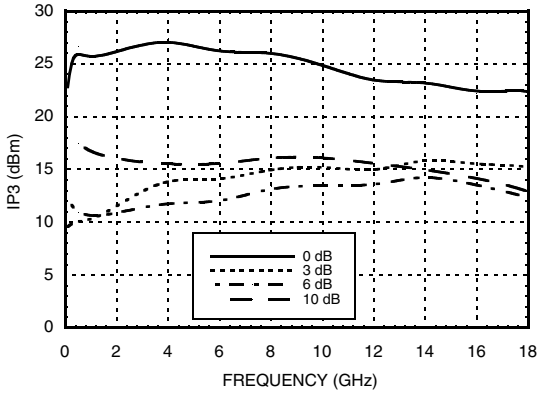
Relative Attenuation vs. Control Voltage @ 10 GHz



Relative Phase vs. Attenuation



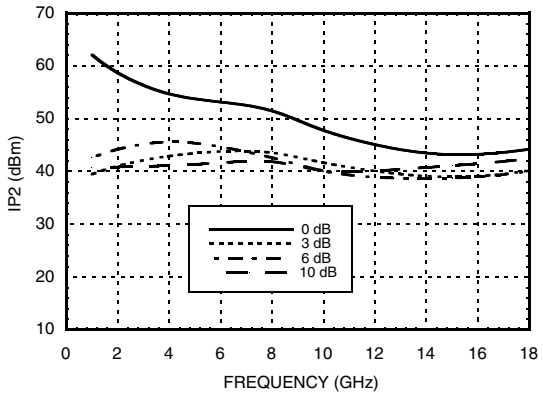
Input IP3 vs. Attenuation*



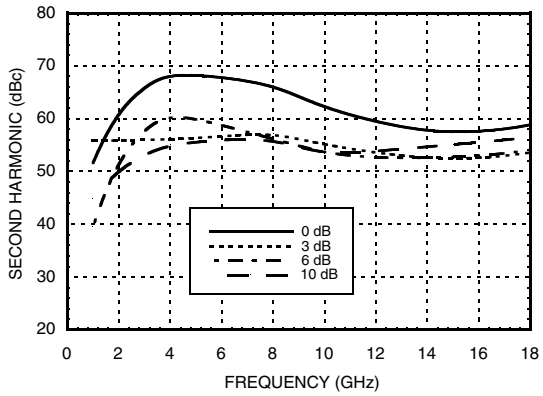
*Two-tone input power = -8 dBm each tone, 1 MHz spacing.

GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz

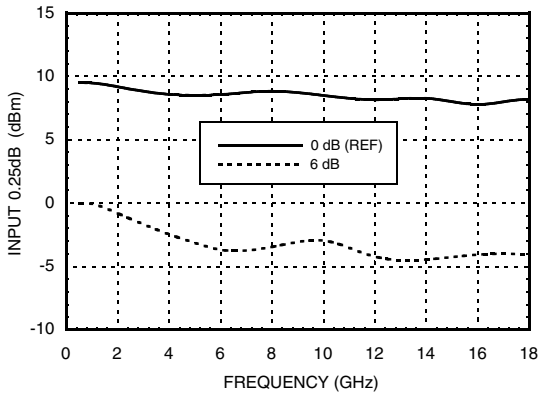
Input IP2 vs. Attenuation*



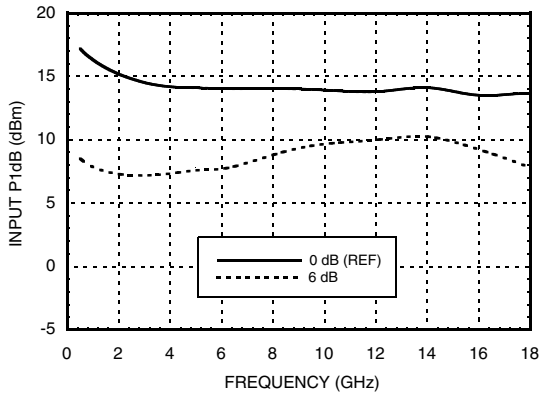
Second Harmonic vs. Attenuation, Pin = -8 dBm



0.25 dB Compression vs. Attenuation



1 dB Compression vs. Attenuation



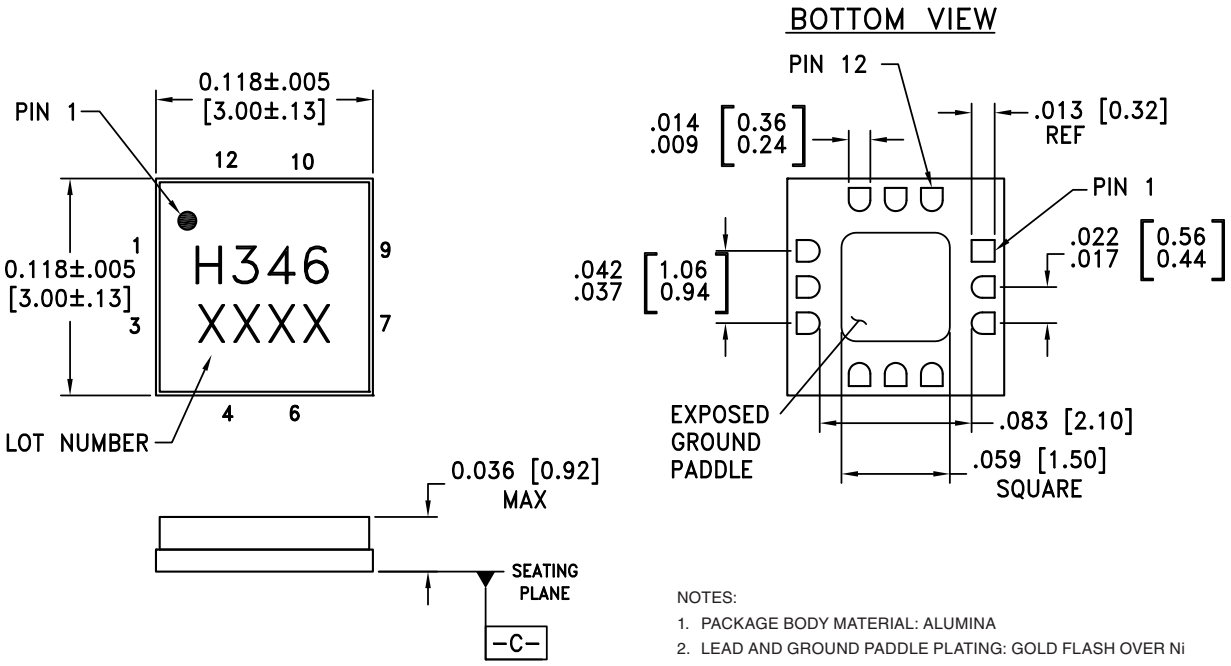
*Two-tone input power = -8 dBm each tone, 1 MHz spacing.

Absolute Maximum Ratings

RF Input Power	+18 dBm
Control Voltage Range	+1 to -5V
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

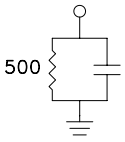
1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER Ni
3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

Package Information

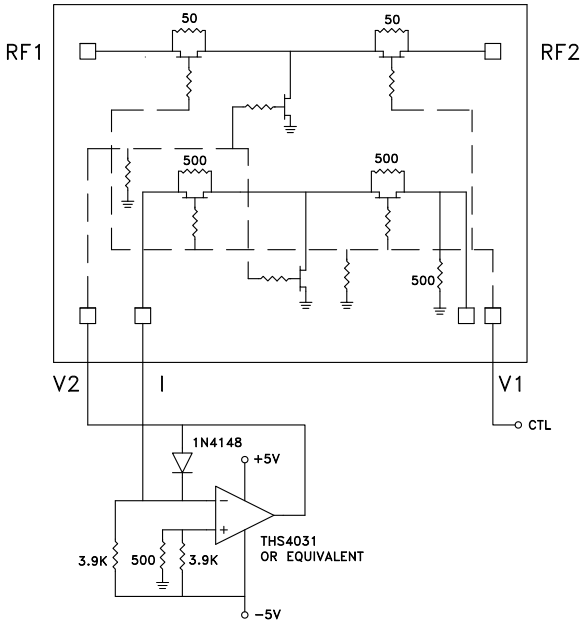
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC346LC3B	Alumina, White	Gold over Nickel	MSL3 [1]	H346 XXXX

[1] Max peak reflow temperature of 260 °C
[2] 4-Digit lot number XXXX

Pin Descriptions

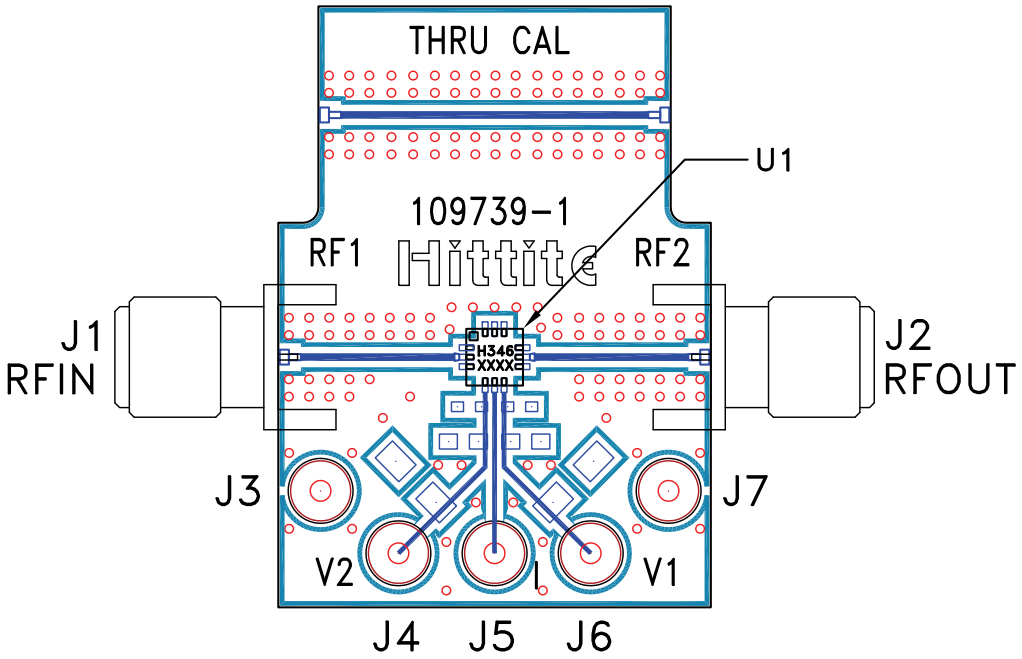
Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	
2, 8	RF1 RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if the RF line potential is not equal to 0V.	
4, 6	V2, V1	Control input (master).	
5	I	Control input (slave).	
10, 11, 12	N/C	This pin may be connected to PCB RF/DC ground. Performance will not be affected.	

Single-Line Control Driver



External op-amp control circuit maintains impedance match while attenuation is varied. Input control ranges from 0 Volts (min. attenuation) to -3.0 Volts (max. attenuation.)

Evaluation PCB



List of Materials for Evaluation PCB 109741 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J7	DC Pin
U1	HMC346LC3B VVA
PCB [2]	109739-1 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should be 50 Ohm impedance and the package ground leads and package bottom should be connected directly to the PCB RF ground plane, similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

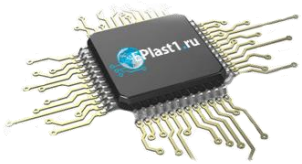
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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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